Nonadiabatic molecular dynamics simulations in large scale nanomaterials and periodic solids

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### Motivation

• Solar energy materials





• Photocatalysis





Bio-imaging



#### **Artificial leaf**





### Nonadiabatic dynamics

• The total wavefunction:

$$\Psi(\mathbf{r}, \mathbf{R}(\mathbf{t})) = \sum_{i} c_i(t) \psi_i(\mathbf{r}, \mathbf{R}(t))$$
$$H_{el}(\mathbf{r}, \mathbf{R}) \psi_i(\mathbf{r}, \mathbf{R}) = E_i \psi_i$$

• The evolution of the electronic amplitudes:

$$i\hbar \frac{\partial c_i(t)}{\partial t} = \sum_j \left( E_i(t)\delta_{i,j} - i\hbar d_{ij}(t) \right) c_j(t)$$
$$d_{ij}(t) = \langle \psi_i \Big| \frac{\partial}{\partial t} \psi_j \rangle$$

• Hammes-Schiffer and Tully method:

$$d_{ij}\left(t + \frac{\Delta t}{2}\right) \approx \frac{\langle \psi_i(t) | \psi_j(t + \Delta t) \rangle - \langle \psi_i(t + \Delta t) | \psi_j(t) \rangle}{2\Delta t}$$

• Stochastic hop from state i to state j with the hopping probability:

$$P_{i \to j}(t, t + \Delta t) = \max\left(0, \frac{\Delta t}{c_i c_i^*} \operatorname{Im}\left(c_i c_j^* d_{ji} - c_j c_i^* d_{ij}\right)\right)$$

Tully, J. Chem. Phys. 1990, 93, 1061 Hammes-Schiffer, Tully, J. Chem. Phys. 1994, 101, 4657–4667



# Challenges

- NA-MD simulations are limited to small-medium sized structures
- Nonadiabatic coupling (NAC) calculations are computationally expensive to calculate for a large number of states

### Goal

• To perform NA-MD calculations for large nanomaterials and periodic solids



# Time-overlap integration

- Grid-based approach using *.cube* files
  - Easy to implement
  - Most codes can output these file
  - Not suitable for large structures with large number of states
- Double-molecule approach
  - Easy to use and can be used in different codes
  - Very time-consuming for large structures
  - Not suitable for periodic structures
- Analytical approach
  - Suitable for large systems and large number of states
  - Recurrence relations for computing integrals: Libint2 package

Smith, Shakiba, Akimov, J. Chem. Theory Comp. 2021, 17, 678–693 Libint, Version 2.6.0 Edward F. Valeev, <u>http://libint.valeyev.net</u>. Shakiba, Stippell, Li, Akimov, J. Chem. Theory Compu. 2022, 18, 5157-5180

LIB/INT

$$\psi_i^* \psi_j dv$$

$$F^{MO} = c^T S^{AO} c$$

$$S^{AO} = \begin{bmatrix} \langle \psi_1 | \psi_1 \rangle & \cdots & \langle \psi_1 | \psi_n \rangle \\ \vdots & \ddots & \vdots \\ \langle \psi_1 | \psi_1 \rangle & \cdots & \langle \psi_1 | \psi_n \rangle \end{bmatrix}$$

 $| \langle \Psi n | \Psi 1 \rangle$ 

## Extending to periodic structures and K-points

• The Bloch function for K-point in a periodic structure is defined as:

$$\beta_a^k(r) = \frac{1}{\sqrt{N}} \sum_R \varphi_a(r-R) e^{ikR}$$

• Overlaps between Bloch functions of two different K-points:

$$S_{a,b}^{k} = \langle \beta_{a}^{k} \left| \beta_{b}^{k'} \right\rangle = \frac{1}{N} \int dr \sum_{R,R'} e^{-ikR} \varphi_{a}^{*}(r-R) e^{ik'R'} \varphi_{b}(r-R')$$
$$= \frac{1}{N} \int dr \sum_{R,R'} e^{i(kR-k'R')} \varphi_{a}^{*}(r-R) \varphi_{b}(r-R')$$



Aradi, Hourahine, Frauenheim, J. Phys. Chem. A 2007, 111, 5678–5684

Shakiba, Stippell, Li, Akimov, J. Chem. Theory Compu. 2022, 18, 5157-5180

#### Implementation



import os
from libra\_py import CP2K\_methods
from libra\_py.workflows.nbra import step2

#### # Setup the parameters

#### if params['is\_periodic']:

params['A\_cell\_vector'] = [28.483, 0.000, 0.000]
params['B\_cell\_vector'] = [0.000, 24.669, 0.000]
params['C\_cell\_vector'] = [0.000, 0.000, 15.000]
# Set the origin and generate the translational vectors
origin = [0,0,0]
# Number of periodic images per each X, -X, Y, -Y, Z, and -Z directions
num\_periodic\_images = [1,1,1]
params['translational\_vectors'] =
CP2K\_methods.generate\_translational\_vectors(origin, num\_periodic\_images

params['periodicity\_type'])

# Run the calculations
step2.run\_cp2k\_libint\_step2(params)

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Applications

- Hot-electron cooling dynamics in silicon nanocrystals (Si NCs)
- Electron-hole recombination dynamics in metal organic frameworks and carbon nitride monolayers



Shakiba, Stippell, Li, Akimov, J. Chem. Theory Compu. 2022, 18, 5157-5180

# Hot-electron cooling dynamics in Si NCs



Bannwarth, Ehlert, Grimme, J. Chem. Theory Comput. 2019, 15, 1652–1671

## Core vs surface atoms

- By increasing size the surface/core DOS decreases
- Core atoms movements are slower than surface atoms

$\sigma_i = \sqrt{\langle (\overrightarrow{r_i} - \langle \overrightarrow{r_i} \rangle) \rangle}$		
System	Si-surface	Si-core
$Si_{59}H_{60}$	0.273	0.172
Si <sub>123</sub> H <sub>100</sub>	0.152	0.113
Si <sub>265</sub> H <sub>140</sub>	0.144	0.114
Si <sub>329</sub> H <sub>172</sub>	0.186	0.141
Si <sub>501</sub> H <sub>228</sub>	0.262	0.190
Si <sub>1009</sub> H <sub>412</sub>	0.169	0.127





#### NA-MD results vs experiment

- Experimental data show a non-monotonic dependence of the relaxation time with respect to NC size
- FSSH and mSDM: Non-monotonic dependence of relaxation time on NC size
- ID-A: Monotonic dependence of relaxation time with increasing NC size



#### Experiment



Bergren, Palomaki, Neale, Furtak, Beard, ACS Nano 2016, 10, 2316–2323

### NA-MD results vs experiment

- By going to larger NCs, the possibility of relaxation happening through non-adjacent states increase
- NA-MD done with only adjacent state transition allowed does not decay for larger structures
- FSSH and mSDM show comparable results but mSDM timescales are larger
- mSDM and FSSH close timescales are due to relatively large dephasing times making correction to coherent amplitudes very small but the overall results are in a better agreement with experiments



llapses periodically to a given
he moment of collapse.

S

 annels for non-adjacent state ways by destroying the coherences ncrease of the ID-A energy

# Charge carrier concentration in C<sub>3</sub>N<sub>4</sub> monolayers

**n m** 

- Intrinsic charge carrier concentration in monolayers are in the range of  $\sim 10^{10}$ - $10^{12}$  cm<sup>-2</sup> in experimental studies
- Theoretical studies overestimate this value due to simulation of excited states in small cell size





# Molecular orbitals in $\rm C_3N_4$ monolayers

- Occupied orbitals are more localized on several melem (triangular repeated motif of 3 fused rings) units
- Unoccupied orbitals are delocalized over multiple connected melem units which is better observed in larger supercells



 $6x6 C_{3}N$ 







# e-h recombination dynamics in C<sub>3</sub>N<sub>4</sub> monolayers





- 100 single-particle excitation states are built from all excitations from the first 10 occupied to the first 10 unoccupied molecular orbitals
- NAC values decrease by increasing supercell size
  - Small time-overlaps between molecular orbitals in large supercells
- Recombination dynamics becomes size-independent for all methods for very large supercell sizes
- For FSSH and mSDM, the dynamics accelerates in the nstates model due to presence of more nonradiative channels for recombination
- The dynamics is slower in ID-A in the n-states model due to presence of more nonradiative channels and therefore more frequent resets of the coherent amplitudes
- For larger supercells, the DOS does not play an important role and the 2- and n-states model show similar results

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#### Summary

- A new methodology for NA-MD simulations in large nanostructures and periodic solids is implemented in the open-source Libra code
- The NAC values decrease by increasing Si NC size and  $C_3N_4$  monolayer supercell size
- A non-monotonic dependence of hot-electron relaxation dynamics on Si NC size was observed in FSSH and mSDM in agreement with experiment
- Non-adjacent transitions play an important role in the relaxation dynamics in Si NCs
- FSSH and mSDM showed similar dynamics in Si NCs due to high dephasing times
- ID-A showed a monotonic dependence of the relaxation time on NC size which was due to multiple coherence resets in the dynamics
- By varying charge carrier concentration using different supercell sizes, a saturation of the recombination timescale was observed showing the size-independence of recombination dynamics in very large structures
- The results of the dynamics in the 2-states and n-states model showed that the inclusion of more states in the dynamics increases the recombination rate by providing more nonradiative channels for the dynamics in the FSSH and mSDM methods
- ID-A showed slower dynamics in the n-states model compared to 2-states model due to frequent coherence resets in the dynamics



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# Thank You!

#### **Questions?**